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## **3 A Output Current, High Speed MOSFET Gate Driver Optocoupler**

# **FOD3182**

#### Description

The FOD3182 is a 3 A Output Current, High Speed MOSFET Gate Drive Optocoupler. It consists of a aluminium gallium arsenide (AlGaAs) light emitting diode optically coupled to a CMOS detector with PMOS and NMOS output power transistors integrated circuit power stage. It is ideally suited for high frequency driving of power MOSFETS used in Plasma Display Panels (PDPs), motor control inverter applications and high performance DC/DC converters.

The device is packaged in an 8-pin dual in-line housing compatible with 260°C reflow processes for lead free solder compliance.

#### Features

- High Noise Immunity Characterized by 50 kV/µs (Typ.) Common Mode Rejection @  $V_{CM}$  = 2,000 V
- Guaranteed Operating Temperature Range of -40°C to +100°C
- 3 A Peak Output Current
- Fast Switching Speed
  - 210 ns Max. Propagation Delay
  - 65 ns Max. Pulse Width Distortion
- Fast Output Rise/Fall Time
- Offers Lower Dynamic Power Dissipation
- 250 kHz Maximum Switching Speed
- Wide V<sub>DD O</sub>perating Range: 10 V to 30 V
- Use of P-Channel MOSFETs at Output Stage Enables Output Voltage Swing Close to the Supply Rail (Rail-to-Rail Output)
- 5000 Vrms, 1 Minute Isolation
- Under Voltage Lockout Protection (UVLO) with Hysteresis -Optimized for Driving MOSFETs
- Minimum Creepage Distance of 8.0 mm
- Minimum Clearance Distance of 10 mm to 16 mm (Option TV or TSV)
- Minimum Insulation Thickness of 0.5 mm
- UL and VDE\*
- 1,414 Peak Working Insulation Voltage (V<sub>IORM</sub>) \*Requires "V" Ordering Option

### Applications

- Plasma Display Panel
- High Performance DC/DC Convertor
- High Performance Switch Mode Power Supply
- High Performance Uninterruptible Power Supply
- Isolated Power MOSFET Gate Drive



### MARKING DIAGRAM



3182 = Device Number

V = VDE Mark (Note: Only appears on parts ordered with DIN EN/IEC 60747-5-2 option - See ordering table)

- = Two Digit Year Code, e.g., "11" XX
- = Digit Work Week Ranging from "01" to "53" YY
- в = Assembly Package Code



### FUNCTIONAL BLOCK DIAGRAM

#### **ORDERING INFORMATION**

See detailed ordering and shipping information on page 16 of this data sheet.

### TRUTH TABLE

LED	V <sub>DD</sub> – V <sub>SS</sub> "Positive Going" (Turn–on)	V <sub>DD</sub> – V <sub>SS</sub> "Negative Going" (Turn–off)	vo
Off	0 V to 30 V	0 V to 30 V	Low
On	0 V to 7.4 V	0 V to 7 V	Low
On	7.4 V to 9 V	7 V to 8.5 V	Transition
On	9 V to 30 V	8.5 V to 30 V	High

#### **PIN DEFINITIONS**

Pin No.	Name	Description
1	NC	Not Connected
2	Anode	LED Anode
3	Cathode	LED Cathode
4	NC	Not Connected
5	V <sub>SS</sub>	Negative Supply Voltage
6	V <sub>O2</sub>	Output Voltage 2 (internally connected to V <sub>O1</sub> )
7	V <sub>O1</sub>	Output Voltage 1
8	V <sub>DD</sub>	Positive Supply Voltage

**SAFETY AND INSULATION RATINGS** (As per DIN EN/IEC 60747–5–2. This optocoupler is suitable for "safe electrical insulation" only within the safety limit data. Compliance with the safety ratings shall be ensured by means of protective circuits.)

Symbol	Parameter	Min.	Тур.	Max.	Unit
	Installation Classifications per DIN VDE 0110/1.89 Table 1				1
	For Rated Mains Voltage < 150 Vrms	-	I–IV	-	
	For Rated Mains Voltage < 300 Vrms	-	I–IV	-	
	For Rated Mains Voltage < 450 Vrms	-	I–III	-	
	For Rated Mains Voltage < 600 Vrms	_	I–III	-	
	For Rated Mains Voltage < 1000 Vrms (Option T, TS)	_	I–III	_	
	Climatic Classification	-	40/100/21	_	
	Pollution Degree (DIN VDE 0110/1.89)	_	2	_	
CTI	Comparative Tracking Index	175	-	_	
V <sub>PR</sub>	Input to Output Test Voltage, Method b, $V_{IORM} \times 1.875 = V_{PR}$ , 100% Production Test with tm = 1 second, Partial Discharge < 5 pC	2651	-	-	
	Input to Output Test Voltage, Method a, $V_{IORM} \times 1.5 = V_{PR}$ , Type and Sample Test with tm = 60 seconds, Partial Discharge < 5 pC	2121	-	_	
V <sub>IORM</sub>	Max Working Insulation Voltage	1,414	-	_	V <sub>peak</sub>
VIOTM	Highest Allowable Over Voltage	6000	-	-	V <sub>peak</sub>
	External Creepage	8	-	-	mm
	External Clearance	7.4	-	-	mm
	External Clearance (for Option T or TS – 0.4" Lead Spacing)	10.16	-	-	mm
	Insulation Thickness	0.5	-	-	mm
T <sub>Case</sub>	Safety Limit Values – Maximum Values Allowed in the Event of a Failure Case Temperature	150	-	_	°C
I <sub>S,INPUT</sub>	Input Current	25	-	_	mA
P <sub>S,OUTPUT</sub>	Output Power (Duty Factor ≤ 2.7%)	250	-	_	mW
R <sub>IO</sub>	Insulation Resistance at T <sub>S</sub> , V <sub>IO</sub> = 500 V	10 <sup>9</sup>	-	_	Ω

#### ABSOLUTE MAXIMUM RATINGS (T<sub>A</sub> = 25°C unless otherwise specified)

Symbol	Parameter	Value	Unit
T <sub>STG</sub>	Storage Temperature	-40 to +125	°C
T <sub>OPR</sub>	Operating Temperature	-40 to +100	°C
Τ <sub>J</sub>	Junction Temperature	-40 to +125	°C
T <sub>SOL</sub>	Lead Solder Temperature – Wave Solder (Refer to Reflow Temperature Profile, page 15)	260 for 10 seconds	°C
I <sub>F(AVG)</sub>	Average Input Current (Note 1)	25	mA
I <sub>F(tr, tf)</sub>	LED Current Minimum Rate of Rise/Fall	250	ns
V <sub>R</sub>	Reverse Input Voltage	5	V
I <sub>OH(PEAK)</sub>	"High" Peak Output Current (Note 2)	3	А
I <sub>OL(PEAK)</sub>	"Low" Peak Output Current (Note 2)	3	А
$V_{DD} - V_{SS}$	Supply Voltage	-0.5 to 35	V
V <sub>O(PEAK)</sub>	Output Voltage	0 to V <sub>DD</sub>	V
Po	Output Power Dissipation (Note 3)	250	mW
PD	Total Power Dissipation (Note 4)	295	mW

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Derate linearly above +79°C free air temperature at a rate of 0.37mA/°C.

2. Maximum pulse width = 10  $\mu$ s, maximum duty cycle = 11%.

3. Derate linearly above +79°C, free air temperature at the rate of 5.73 mW/°C.

4. No derating required across operating temperature range.

#### **RECOMMENDED OPERATING CONDITIONS**

Symbol	Parameter	Value	Unit
$V_{DD} - V_{SS}$	Power Supply	10 to 30	V
I <sub>F(ON)</sub>	Input Current (ON)	10 to 16	mA
V <sub>F(OFF)</sub>	Input Voltage (OFF)	-3.0 to 0.8	V

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

Symbol	Parameter	Test Conditions	Min	Тур	Max	Unit
I <sub>OH</sub>	High Level Output Current	V <sub>OH</sub> = (V <sub>DD</sub> - V <sub>SS</sub> - 1 V)	0.5	0.9	-	А
		$V_{OH} = (V_{DD} - V_{SS} - 6 V)$	2.5	_	-	
I <sub>OL</sub>	Low Level Output Current	$V_{OL} = (V_{DD} - V_{SS} + 1 V)$	0.5	1	-	А
		$V_{OL} = (V_{DD} - V_{SS} + 6 V)$	2.5	_	-	
V <sub>OH</sub>	High Level Output Voltage (Note 5, 6)	I <sub>O</sub> = -100 mA	V <sub>DD</sub> – 0.5	_	-	V
V <sub>OL</sub>	Low Level Output Voltage (Note 5, 6)	I <sub>O</sub> = 100 mA	-	_	V <sub>SS</sub> + 0.5	V
I <sub>DDH</sub>	High Level Supply Current	Output Open, I <sub>F</sub> = 10 to 16 mA	-	2.6	4.0	mA
I <sub>DDL</sub>	Low Level Supply Current	Output Open, $V_F = -3.0$ to 0.8 V	-	2.5	4.0	mA
I <sub>FLH</sub>	Threshold Input Current Low to High	I <sub>O</sub> = 0 mA, V <sub>O</sub> > 5 V	-	3.0	7.5	mA
$V_{FHL}$	Threshold Input Voltage High to Low	I <sub>O</sub> = 0 mA, V <sub>O</sub> < 5 V	0.8	-	-	V
V <sub>F</sub>	Input Forward Voltage	I <sub>F</sub> = 10 mA	1.1	1.43	1.8	V
$\Delta V_{F}/T_{A}$	Temperature Coefficient of Forward Voltage	I <sub>F</sub> = 10 mA	-	-1.5	-	mV/°C
V <sub>UVLO+</sub>	UVLO Threshold	V <sub>O</sub> > 5V, I <sub>F</sub> = 10 mA	7	8.3	9	V
V <sub>UVLO</sub> _		V <sub>O</sub> < 5V, I <sub>F</sub> = 10 mA	6.5	7.7	8.5	V
JVLO <sub>HYST</sub>	UVLO Hysteresis		-	0.6	-	V
BV <sub>R</sub>	Input Reverse Breakdown Voltage	I <sub>R</sub> = 10 μA	5	-	-	V
CIN	Input Capacitance	f = 1 MHz, V <sub>F</sub> = 0 V	-	25	-	pF

ELECTRICAL-OPTICAL CHARACTERISTICS (DC) (Apply over all recommended conditions, typical value is measured at	
$V_{DD}$ = 30 V, $V_{SS}$ = 0 V, $T_A$ = 25°C, unless otherwise specified.)	

In this test, V<sub>OH</sub> is measured with a dc load current of 100 mA. When driving capacitive load V<sub>OH</sub> will approach V<sub>DD</sub> as I<sub>OH</sub> approaches zero amps.
Maximum pulse width = 1 ms, maximum duty cycle = 20%.

SWITCHING CHARACTERISTICS (Apply over all recommended conditions, typical value is measured at V<sub>DD</sub> = 30 V, V<sub>SS</sub> = 0 V,  $T_A = 25^{\circ}C$ , unless otherwise specified.)

Symbol	Parameter	Test Conditions	Min	Тур	Max	Unit
t <sub>PLH</sub>	Propagation Delay Time to High Output Level (Note 7)	$I_{\rm F} = 10 \text{ mA}, R_{\rm g} = 10 \Omega,$	50	120	210	ns
t <sub>PHL</sub>	Propagation Delay Time to Low Output Level (Note 7)	f = 250 kHz, Duty Cycle = 50%,	50	145	210	ns
P <sub>WD</sub>	Pulse Width Distortion (Note 8)	C <sub>g</sub> = 10 nF	-	35	65	ns
P <sub>DD</sub> (t <sub>PHL</sub> – t <sub>PLH</sub> )	Propagation Delay Difference Between Any Two Parts (Note 9)		-90	-	90	ns
t <sub>r</sub>	Rise Time	$C_L$ = 10 nF, $R_g$ = 10 $\Omega$	-	38	-	ns
t <sub>f</sub>	Fall Time		-	24	-	ns
t <sub>UVLO ON</sub>	UVLO Turn On Delay		-	2.0	-	μs
t <sub>UVLO</sub> OFF	UVLO Turn Off Delay		-	0.3	-	μs
CM <sub>H</sub>	Output High Level Common Mode Transient Immunity (Note 10, 11)	$ \begin{array}{l} T_{A}=+25^{\circ}C,\ I_{f}=7\ mA\ to\\ 16\ mA,\ V_{CM}=2\ kV,\\ V_{DD}=30\ V \end{array} $	35	50	-	kV/μs
CM <sub>L</sub>	Output Low Level Common Mode Transient Immunity (Note 10, 12)	$ \begin{array}{l} T_{A}=+25^{\circ}C, \ V_{f}=0 \ V, \\ V_{CM}=2 \ kV, \ V_{DD}=30 \ V \end{array} $	35	50	-	kV/μs

t<sub>PHL</sub> propagation delay is measured from the 50% level on the falling edge of the input pulse to the 50% level of the falling edge of the V<sub>O</sub> 7. signal. t<sub>PLH</sub> propagation delay is measured from the 50% level on the rising edge of the input pulse to the 50% level of the rising edge of the Vo signal.

PWD is defined as | t<sub>PHL</sub> - t<sub>PLH</sub> | for any given device.
The difference between t<sub>PHL</sub> and t<sub>PLH</sub> between any two FOD3182 parts under same operating conditions, with equal loads.

10. Pin 1 and 4 need to be connected to LED common.

11. Common mode transient immunity in the high state is the maximum tolerable dV<sub>CM</sub>/dt of the common mode pulse V<sub>CM</sub> to assure that the output will remain in the high state (i.e.  $V_0 > 15$  V).

12. Common mode transient immunity in a low state is the maximum tolerable dV<sub>CM</sub>/dt of the common mode pulse, V<sub>CM</sub>, to assure that the output will remain in a low state (i.e.  $V_0 < 1.0$  V).

#### INSULATION CHARACTERISTICS

Symbol	Parameter	Test Conditions	Min	Тур*	Max	Unit
V <sub>ISO</sub>	Withstand Isolation Voltage (Note 13, 14)	$\begin{array}{l} T_{A} = 25^{\circ}C, \ R.H. < 50\%, \\ t = 1 \ minute, \ I_{I-O} \leq 10 \ \mu A \end{array}$	5000	-	-	V <sub>rms</sub>
R <sub>I-O</sub>	Resistance (Input to Output) (Note 14)	V <sub>I-O</sub> = 500 V	-	10 <sup>11</sup>	-	Ω
C <sub>I-O</sub>	Capacitance (Input to Output)	Freq. = 1 MHz	-	1	-	pF

\*Typical values at T<sub>A</sub> = 25°C

13. In accordance with UL 1577, each optocoupler is proof tested by applying an insulation test voltage > 6000 Vrms, 60 Hz for 1 second (leakage detection current limit  $I_{I-O} < 10 \ \mu A$ ).

14. Device considered a two-terminal device: pins on input side shorted together and pins on output side shorted together.

#### **TYPICAL PERFORMANCE CURVES**







Figure 3. Output High Current vs. Ambient Temperature





Figure 2. Output High Voltage Drop vs. Ambient Temperature



Figure 4. Output High Current vs. Ambient Temperature



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#### TYPICAL PERFORMANCE CURVES (Continued)



#### TYPICAL PERFORMANCE CURVES (Continued)



### TYPICAL PERFORMANCE CURVES (Continued)



Figure 19. Under Voltage Lockout

### **TEST CIRCUIT**



 $\label{eq:conditions:} \hline Frequency = 200 \ Hz \\ Duty Cycle = 0.2\% \\ V_{DD} = 10 \ V \ to \ 30 \ V \\ V_{SS} = 0 \ V \\ I_F = 10 \ mA \ to \ 16 \ mA \\ \hline \end{array}$ 





Figure 23. V<sub>OL</sub> Test Circuit



Figure 24. I<sub>DDH</sub> Test Circuit



Figure 25. I<sub>DDL</sub> Test Circuit







Figure 29.  $t_{PHL}$ ,  $t_{PLH}$ ,  $t_r$  and  $t_f$  Test Circuit and Waveforms





### **REFLOW PROFILE**



Figure 31. Reflow Profile

#### Table 1.

Profile Freature	Pb-Free Assembly Profile
Temperature Min. (Tsmin)	150°C
Temperature Max. (Tsmax)	200°C
Time (t <sub>S</sub> ) from (Tsmin to Tsmax)	60–120 seconds
Ramp-up Rate (t <sub>L</sub> to t <sub>P</sub> )	3°C/second max.
Liquidous Temperature (TL)	217°C
Time ( $t_L$ ) Maintained Above ( $T_L$ )	60–150 seconds
Peak Body Package Temperature	260°C +0°C / –5°C
Time (t <sub>P</sub> ) within 5°C of 260°C	30 seconds
Ramp-down Rate (T <sub>P</sub> to T <sub>L</sub> )	6°C/second max.
Time 25°C to Peak Temperature	8 minutes max.

### **ORDERING INFORMATION**

Part Number	Package	Shipping <sup>†</sup>
FOD3182	PDIP8 9.655x6.61, 2.54P DIP 8-Pin	50 Units / Tube
FOD3182S	PDIP8 GW SMT 8-Pin (Lead Bend)	50 Units / Tube
FOD3182SD	FOD3182SD PDIP8 GW SMT 8-Pin (Lead Bend)	
FOD3182V	PDIP8 9.655x6.61, 2.54P DIP 8–Pin, IEC60747–5–2 option	50 Units / Tube
FOD3182SV PDIP8 GW SMT 8-Pin (Lead Bend), DIN EN/IEC 60747-5-2 optio		50 Units / Tube
FOD3182SDV	PDIP8 GW SMT 8-Pin (Lead Bend), DIN EN/IEC 60747-5-2 option	1,000 / Tape and Reel
FOD3182TV	PDIP8 6.6x3.81, 2.54P DIP 8–Pin, 0.4" Lead Spacing, DIN EN/IEC 60747–5–2 option	50 Units / Tube
FOD3182TSV PDIP8 GW SMT 8-Pin, 0.4" Lead Spacing, DIN EN/IEC 60747-5-2 option		50 Units / Tube
FOD3182TSR2	PDIP8 GW SMT 8-Pin, 0.4" Lead Spacing	700 / Tape and Reel
FOD3182TSR2V	PDIP8 GW SMT 8-Pin, 0.4" Lead Spacing, DIN EN/IEC 60747-5-2 option	700 / Tape and Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.



PDIP8 6.6x3.81, 2.54P CASE 646BW ISSUE O

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